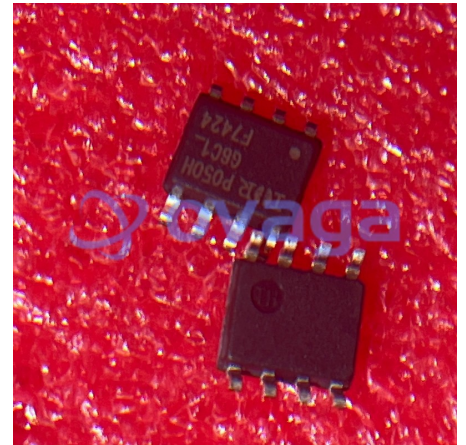


MOSFET, Power, P-Ch; VDSS -30V; RDS(ON) 13.5 Milliohms; ID -11A; SO-8; PD 2.5W; gFS 17S

Manufacturers	Infineon Technologies Corporation
Package/Case	SOIC-8
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for IRF7424PBF or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

These P-Channel MOSFETs from International Rectifier utilize advanced processing techniques to achieve the extremely low on-resistance per silicon area. This benefit provides the designer with an extremely efficient device for use in battery and load management applications..

- Ultra Low On-Resistance
- P-Channel MOSFET
- Surface Mount
- Available in Tape & Reel

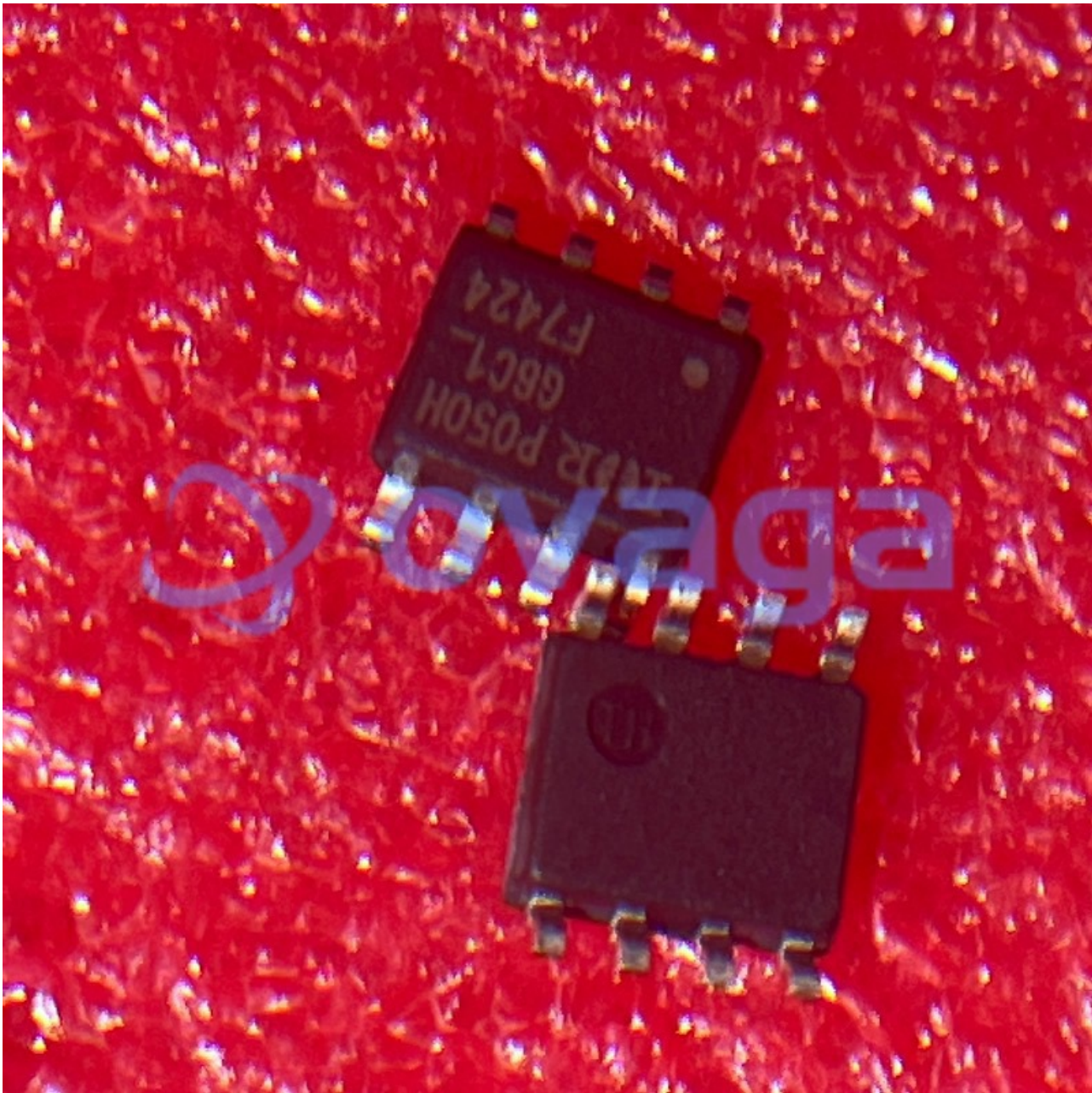
Features

RoHS Compliant

Industry-leading quality

Industry-Standard Pinout

P-Channel MOSFET

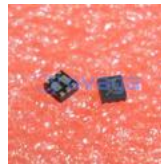


Related Products



[IRLTS6342TRPBF](#)

Infineon Technologies Corporation
TSOP-6



[IRLHS6376TRPBF](#)

Infineon Technologies Corporation
PQFN2x2DD



[IRF9310PBF](#)

Infineon Technologies Corporation
SOIC-8



[IRFH9310TRPBF](#)

Infineon Technologies Corporation
PQFN-8



[IRF9358TRPBF](#)

Infineon Technologies Corporation
SOP-8



[IRFB7430PBF](#)

Infineon Technologies Corporation
TO-220



[IRFB3307ZPBF](#)

Infineon Technologies Corporation
TO-220AB



[IRF7351TRPBF](#)

Infineon Technologies Corporation
SOIC-8